



**POWERDI<sup>®</sup>** 

### **Product Summary**

V <sub>(BR)</sub> dss	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-20V	8mΩ @ V <sub>GS</sub> = -4.5V	-12A
	9.8mΩ @ V <sub>GS</sub> = -2.5V	-10A
	13mΩ @ V <sub>GS</sub> = -1.8V	-9.3A
	17mΩ @ V <sub>GS</sub> = -1.5V	-8.3A

# Description

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# **Applications**

- Load Switch
- Power Management Functions

#### Features

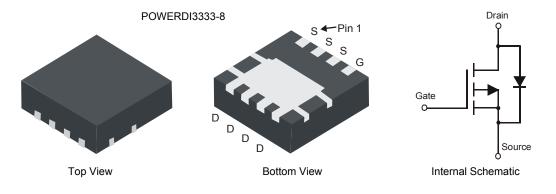
- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product

20V P-CHANNEL ENHANCEMENT MODE MOSFET

- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

### **Mechanical Data**

- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (approximate)



### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2008UFG-7	POWERDI3333-8	2000/Tape & Reel
DMP2008UFG-13	POWERDI3333-8	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

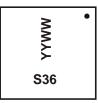
#### 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

Notes:

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

# **Marking Information**



S36 = Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 11 = 2011) WW = Week code (01 ~ 53)



### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage	V <sub>DSS</sub>	-20	V		
Gate-Source Voltage (Note 5)	V <sub>GSS</sub>	±8	V		
Continuous Drain Current (Note 6) $V_{GS}$ = -4.5V	ID	-12 -9.5 -54	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)		I <sub>DM</sub>	-80	A	
Maximum Continuous Body Diode Forward Current		I <sub>S</sub>	-2.2	A	
Avalanche Current (Note 8)			I <sub>AS</sub>	-15	A
Avalanche Energy (Note 8)			E <sub>AS</sub>	-113	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	Р	2.2	W
Total Power Dissipation (Note 0)	T <sub>C</sub> = +25°C	PD	41	
Thermal Resistance, Junction to Ambient	(Note 5)	D.	59	°C/W
	(Note 6)	R <sub>0JA</sub>	137	
Thermal Resistance, Junction to Case (Note 6)	Rejc	3.0		
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						·
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-1	μA	V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>		—	±100	nA	$V_{GS}$ = ±8V, $V_{DS}$ = 0V
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.4	—	-1.0	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
			—	8	mΩ	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -12A
Static Drain-Source On-Resistance	Dec (cu)		_	9.8		V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -10A
	R <sub>DS</sub> (ON)		—	13	1115.2	V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -9.3A
			—	17		V <sub>GS</sub> = -1.5V, I <sub>D</sub> = -8.3A
Forward Transfer Admittance	Y <sub>fs</sub>	_	42	_	S	V <sub>DS</sub> = -5V, I <sub>D</sub> = -12A
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	Ciss		6909	—		
Output Capacitance	Coss		635	—	pF	$V_{DS}$ = -10V, $V_{GS}$ = 0V f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	563	_		1 - 1.000112
Gate Resistance	R <sub>G</sub>	Ι	2.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	72	_		
Total Gate Charge (V <sub>GS</sub> = -2.5V)	Qg	_	40	_	nC	$y_{1} = 40y_{1} = 400$
Gate-Source Charge	Q <sub>gs</sub>	_	8.6	_	nc	$V_{DD} = -10V, I_D = -12A$
Gate-Drain Charge	Q <sub>gd</sub>	_	14.5	_		
Turn-On Delay Time	t <sub>D(on)</sub>	_	22	_		
Turn-On Rise Time	tr	_	33	—		V <sub>GS</sub> = -4.5V, V <sub>DD</sub> = -10V,
Turn-Off Delay Time	t <sub>D(off)</sub>	_	291	_	ns	R <sub>G</sub> = 6Ω, I <sub>D</sub> = -12A
Turn-Off Fall Time	t <sub>f</sub>	_	124	_		
BODY DIODE CHARACTERISTICS	•		·	·		·
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	_	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -12A
	V SD	_	-0.7	—	V	$V_{GS} = 0V, I_{S} = -2A$
Reverse Recovery Time (Note 10)	t <sub>rr</sub>		25	_	ns	I <sub>F</sub> = -12A, di/dt = 100A/µs
Reverse Recovery Charge (Note 10)	Qrr		15	_	nC	I <sub>F</sub> = -12A, di/dt = 100A/µs

Notes: 5. AEC-Q101 V<sub>GS</sub> maximum is  $\pm 6.4$ V.

8 .UIS in production with L = 1mH,  $T_{\rm J}$  = +25°C

9. Short duration pulse test used to minimize self-heating effect.

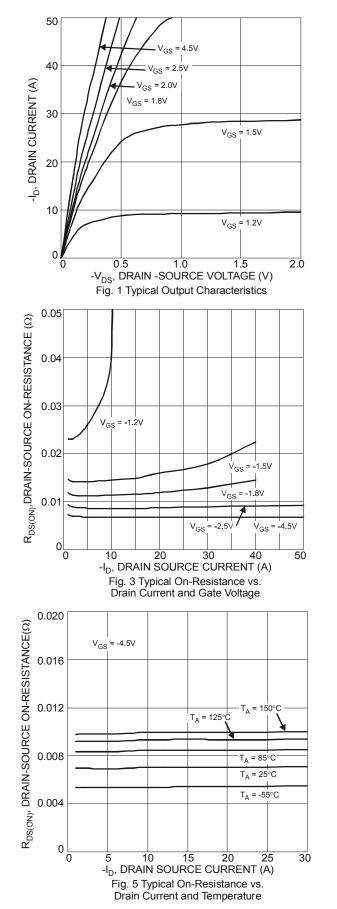
10. Guaranteed by design. Not subject to product testing.

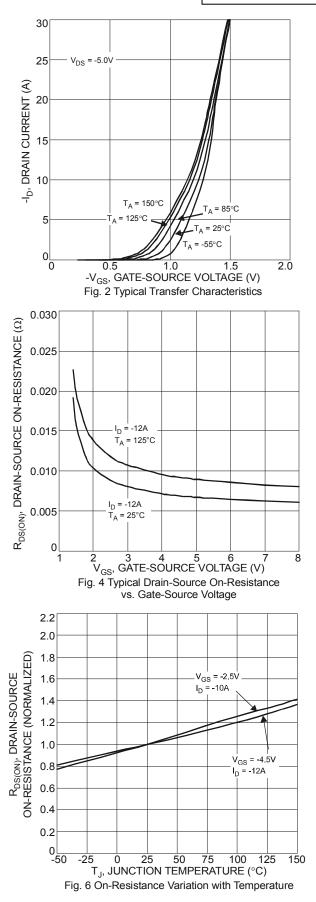
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<sup>6.</sup> ReJA is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. ReJC is guaranteed by design while Re<sub>JA</sub> is determined by the user's board design. 7. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

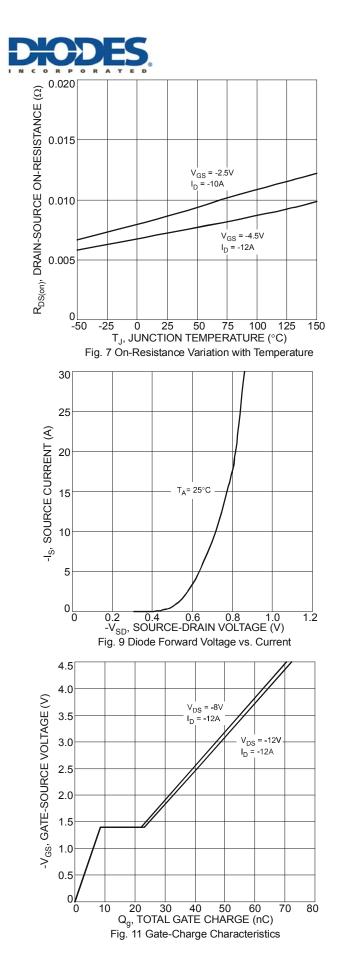


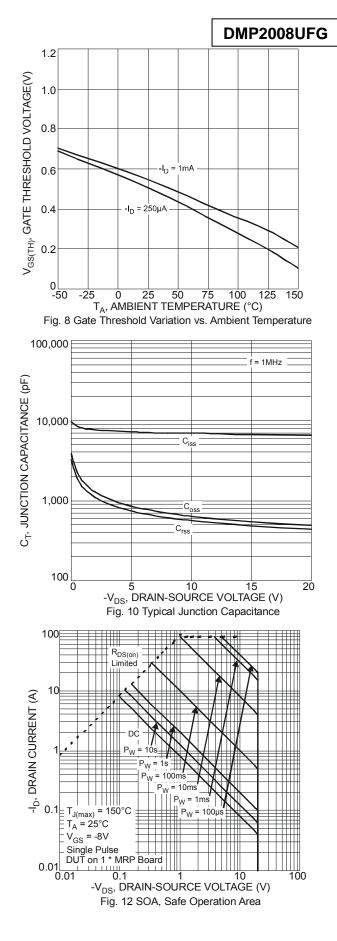
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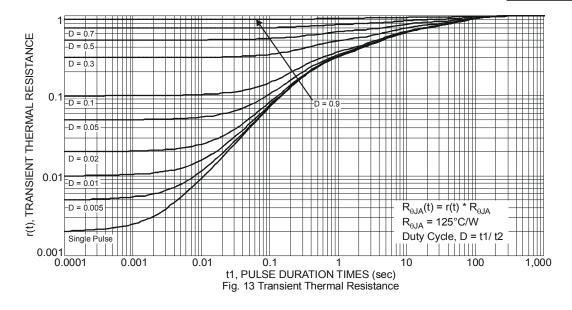
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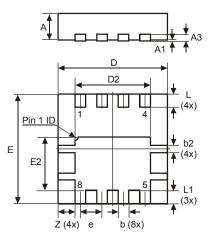
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# **Package Outline Dimensions**

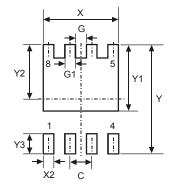
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
ш	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	-	-	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Ζ	_	_	0.515		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.420			
Y	3.700			
Y1	2.250			
Y2	1.850			
Y3	0.700			
Х	2.370			
X2	0.420			

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